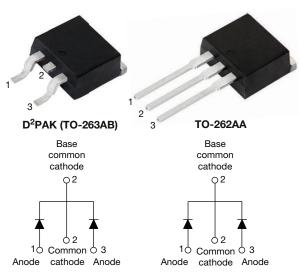


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High Performance Schottky Rectifier, 2 x 15 A



VS-25CTQ...S-M3

VS-25CTQ...-1-M3

PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 15 A					
V _R	35 V, 40 V, 45 V					
V _F at I _F	0.50 V					
I _{RM} typ.	70 mA at 125 °C					
T _J max.	150 °C					
E _{AS}	20 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Very low forward voltage drop
- High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 $^{\circ}\mathrm{C}$
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-25CTQ... center tap Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS	IAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	30	А			
V _{RRM}	Range	35 to 45	V			
I _{FSM}	t _p = 5 μs sine	990	A			
V _F	15 A_{pk} , $T_J = 125 \text{ °C}$ (per leg)	0.50	V			
Т _Ј	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-25CTQ035S-M3 VS-25CTQ035-1-M3	VS-25CTQ040S-M3 VS-25CTQ040-1-M3	VS-25CTQ045S-M3 VS-25CTQ045-1-M3	UNITS
Maximum DC reverse voltage	V _R	35	40	45	V
Maximum working peak reverse voltage	V _{RWM}		40	40	v

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ABSOLUTE MAXIMUM RATIN	GS				
PARAMETER	SYMBOL	TEST COND	TIONS	VALUES	UNITS
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 102 °C	c, rectangular waveform	30	
Maximum peak one cycle		5 µs sine or 3 µs rect. pulse	Following any rated	990	A
non-repetitive surge current per leg See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	load condition and with rated V _{RRM} applied	250	
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 3 \ A, \ L = 4.40 \ r$	mH	20	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	А

ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
Maximum forward voltage drop per leg See fig. 1		15 A	T _{.1} = 25 °C	0.56				
	V _{FM} ⁽¹⁾	30 A	1j=25 C	0.71	v			
	V FM (*)	15 A	T.I = 125 °C	0.50				
		30 A	1j=125 C	0.64				
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1.75	mA			
per leg	IRM (')	T _J = 125 °C	VR - naleu VR	110				
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	70	mA			
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		900	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHA	NICAL SPI	ECIFICA	TIONS		
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to 150	°C
Maximum thermal resistance, junction to case per leg		P	DC operation See fig. 4	3.25	
Maximum thermal resistance junction to case per package	,	R _{thJC}	DC operation	1.63	°C/W
Typical thermal resistance, case to heatsink			Mounting surface, smooth and greased	0.50	
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf ∙ in)
Marking device			Case style D ² PAK (TO-263AB)		035S 040S 045S
			Case style TO-262AA	25CTQ0 25CTQ0 25CTQ0 25CTQ0	040-1



1000

100

10

1

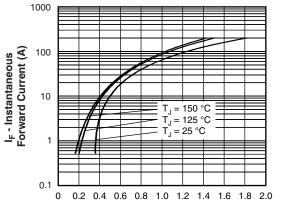
0.1

0.01

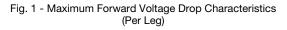
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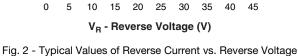
I_R - Reverse Current (mA)

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V_{FM} - Forward Voltage Drop (V)





T_{.1} = 150 °C

T_J = 125 °C

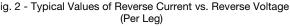
 $T_J = 100 \degree C$

T_J = 75 °C

= 25 °C

= 50 °C

Т



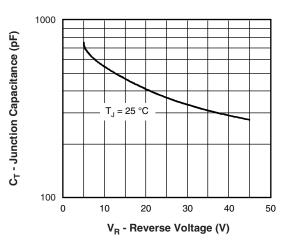


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

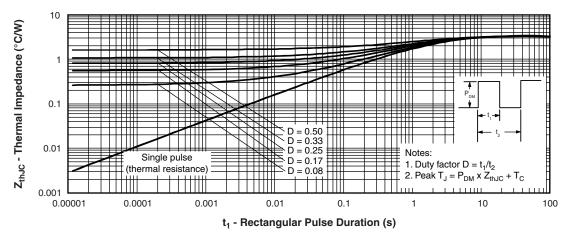


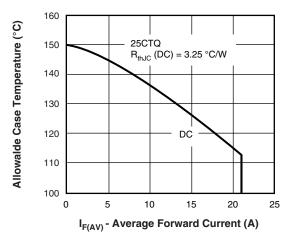
Fig. 4 - Maximum Thermal Impedance $\mathsf{Z}_{\mathsf{thJC}}$ Characteristics (Per Leg)

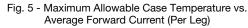
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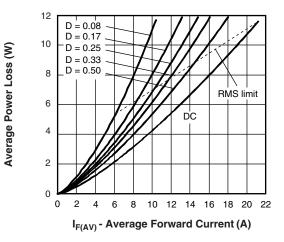


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

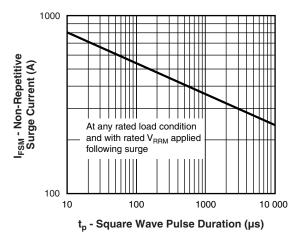


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

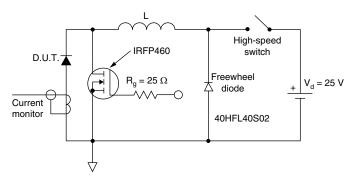


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- $\begin{array}{l} \mbox{Pd} = \mbox{forward power loss} = \mbox{I}_{F(AV)} \times \mbox{V}_{FM} \mbox{ at } (\mbox{I}_{F(AV)}/\mbox{D}) \mbox{ (see fig. 6);} \\ \mbox{Pd}_{REV} = \mbox{inverse power loss} = \mbox{V}_{R1} \times \mbox{I}_{R} \mbox{ (1 D); } \mbox{I}_{R} \mbox{ at } \mbox{V}_{R1} = 80 \ \% \mbox{ rated } \mbox{V}_{R1} \end{array}$

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ORDERING INFORMATION TABLE

Device code	VS-	25	С	т	Q	045	S	TRL	-M3
	\cup	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
	1.	- Visl	nay Sem	nicondu	ctors pr	oduct			
	2 -	- Cur	rent rati	ing (25 A	4)				
	3 - Circuit configuration: C = common cathode								
	4 -	- T=	TO-220)					
	5 -	- Sch	ottky "O	Q" series	s [035 = 3	35 V		
	6	- Vol	tage rati	ings —		040 = 4			
	7 -	• \$	= D ² PA	K (TO-2	63AB) [045 = 4	45 V		
	_	• -1	= TO-2	262AA					
	8 -	• N	one = tu	lbe					
		• TI	RL = tap	be and r	eel (left	orienteo	d - for D	² PAK o	nly)
	_			be and r					• ·
	9 -	-M3	s = halog	gen-free	, RoHS	-complia	ant, and	termin	ation le

ORDERING INFORMATION						
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION				
VS-25CTQ035S-M3	50	Antistatic plastic tubes				
VS-25CTQ035STRL-M3	800	13" diameter plastic tape and reel				
VS-25CTQ035STRR-M3	800	13" diameter plastic tape and reel				
VS-25CTQ040S-M3	50	Antistatic plastic tubes				
VS-25CTQ040STRL-M3	800	13" diameter plastic tape and reel				
VS-25CTQ040STRR-M3	800	13" diameter plastic tape and reel				
VS-25CTQ045S-M3	50	Antistatic plastic tubes				
VS-25CTQ045STRL-M3	800	13" diameter plastic tape and reel				
VS-25CTQ045STRR-M3	800	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS							
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164					
Dimensions	TO-262AA	www.vishay.com/doc?96165					
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444					
Part marking information	TO-262AA	www.vishay.com/doc?95443					
Packaging information		www.vishay.com/doc?96424					
SPICE model		www.vishay.com/doc?95285					

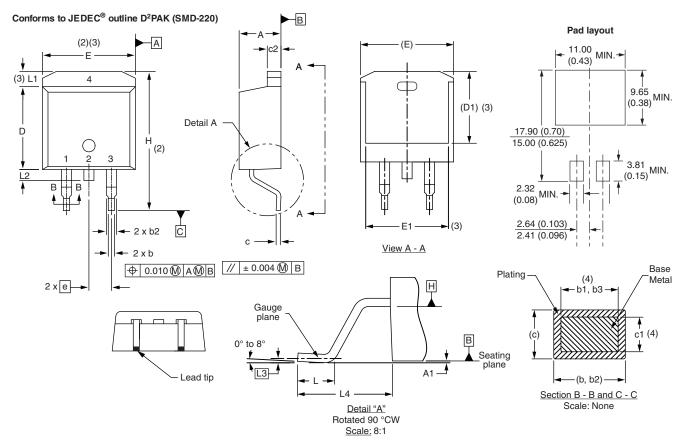


Outline Dimensions

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DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070		Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
с	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065		L3	0.25	BSC	0.010) BSC	
D	8.51	9.65	0.335	0.380	2	L4	4.78	5.28	0.188	0.208	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 08-Jul-15

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Document Number: 95046

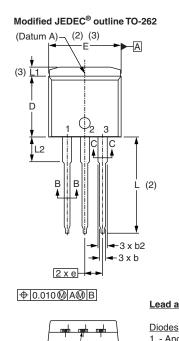


Outline Dimensions

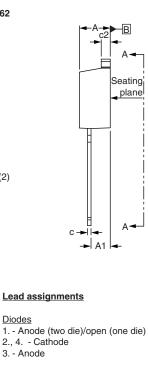
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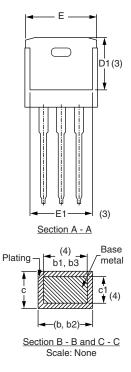
TO-262

DIMENSIONS in millimeters and inches



Lead tip





	MILLIN	IETERS	INC	INCHES			
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	BSC	0.100	BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

(4) Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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Document Number: 95419





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